Low Offset Voltage Dual Comparators

The LM393 series are dual independent precision voltage comparators capable of single or split supply operation. These devices are designed to permit a common mode range-to-ground level with single supply operation. Input offset voltage specifications as low as 2.0 mV make this device an excellent selection for many applications in consumer, automotive, and industrial electronics.

Features

- Wide Single–Supply Range: 2.0 Vdc to 36 Vdc
- Split–Supply Range: ±1.0 Vdc to ±18 Vdc
- Very Low Current Drain Independent of Supply Voltage: 0.4 mA
- Low Input Bias Current: 25 nA
- Low Input Offset Current: 5.0 nA
- Low Input Offset Voltage: 5.0 mV (max) LM293/393
- Input Common Mode Range to Ground Level
- Differential Input Voltage Range Equal to Power Supply Voltage
- Output Voltage Compatible with DTL, ECL, TTL, MOS, and CMOS Logic Levels
- ESD Clamps on the Inputs Increase the Ruggedness of the Device without Affecting Performance
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

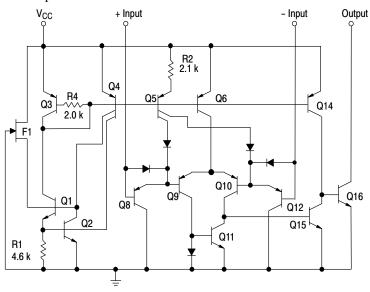
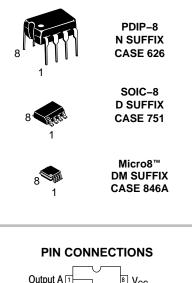


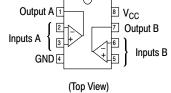
Figure 1. Representative Schematic Diagram (Diagram shown is for 1 comparator)



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DEVICE MARKING AND ORDERING INFORMATION

See detailed marking information and ordering and shipping information on pages 6 and 7 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage	V _{CC}	+36 or ±18	V
Input Differential Voltage	V _{IDR}	36	V
Input Common Mode Voltage Range (Note 1)	V _{ICR}	-0.3 to +36	V
Output Voltage	V _O	36	V
Output Short Circuit–to–Ground Output Sink Current (Note 2)	I _{SC} I _{Sink}	Continuous 20	mA
Power Dissipation @ $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P _D 1/R _{θJA}	570 5.7	mW mW/°C
Operating Ambient Temperature Range LM293 LM393, LM393E LM2903, LM2903E LM2903V, NCV2903 (Note 3)	T _A	-25 to +85 0 to +70 -40 to +105 -40 to +125	°C
Maximum Operating Junction Temperature LM393, LM393E, LM2903, LM2903E, LM2903V LM293, NCV2903	T _{J(max)}	150 150	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

For supply voltages less than 36 V, the absolute maximum input voltage is equal to the supply voltage.
 The maximum output current may be as high as 20 mA, independent of the magnitude of V_{CC}, output short circuits to V_{CC} can cause excessive heating and eventual destruction.

3. NCV2903 is qualified for automotive use.

ESD RATINGS

Rating	НВМ	ММ	Unit
ESD Protection at any Pin (Human Body Model – HBM, Machine Model – MM)			
NCV2903 (Note 3)	2000	200	V
LM393E, LM2903E	1500	150	V
LM393DG/DR2G, LM2903DG/DR2G	250	100	V
All Other Devices	1500	150	V

		LM293, LM393, LM393E			LM2903/E/V, NCV2903			
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage (Note 5) $T_A = 25^{\circ}C$ $T_{low} \le T_A \le T_{high}$	V _{IO}		±1.0 _	±5.0 ±9.0		±2.0 ±9.0	±7.0 ±15	mV
Input Offset Current $T_A = 25^{\circ}C$ $T_{low} \le T_A \le T_{high}$	I _{IO}		±5.0 _	±50 ±150		±5.0 ±50	±50 ±200	nA
Input Bias Current (Note 6) $T_A = 25^{\circ}C$ $T_{low} \le T_A \le T_{high}$	I _{IB}		20 -	250 400		20 20	250 500	nA
Input Common Mode Voltage Range (Note 6) $T_A = 25^{\circ}C$ $T_{low} \le T_A \le T_{high}$	V _{ICR}	0 0	-	V _{CC} –1.5 V _{CC} –2.0	0 0		V _{CC} –1.5 V _{CC} –2.0	V
Voltage Gain $R_L \ge 15 \text{ k}\Omega$, V_{CC} = 15 Vdc, T_A = 25°C	A _{VOL}	50	200	-	25	200	-	V/mV
Large Signal Response Time $V_{in} = TTL$ Logic Swing, $V_{ref} = 1.4$ Vdc $V_{RL} = 5.0$ Vdc, $R_L = 5.1$ k Ω , $T_A = 25^{\circ}$ C	-	-	300	-	-	300	-	ns
Response Time (Note 8) $V_{RL} = 5.0 \text{ Vdc}, R_L = 5.1 \text{ k}\Omega, T_A = 25^{\circ}\text{C}$	t _{тLH}	-	1.3	-	-	1.5	-	μs
Input Differential Voltage (Note 9) All $V_{in} \ge GND$ or V– Supply (if used)	V _{ID}	-	-	V _{CC}	-	-	V _{CC}	V
Output Sink Current $V_{in} \ge 1.0$ Vdc, $V_{in+} = 0$ Vdc, $V_O \le 1.5$ Vdc $T_A = 25^{\circ}C$	I _{Sink}	6.0	16	-	6.0	16	-	mA
	V _{OL}	-	150 -	400 700	-	_ 200	400 700	mV
$ \begin{array}{l} \text{Output Leakage Current} \\ \text{V}_{in-} = 0 \text{ V}, \text{ V}_{in+} \geq 1.0 \text{ Vdc}, \text{ V}_{O} = 5.0 \text{ Vdc}, \text{ T}_{A} = 25^{\circ}\text{C} \\ \text{V}_{in-} = 0 \text{ V}, \text{ V}_{in+} \geq 1.0 \text{ Vdc}, \text{ V}_{O} = 30 \text{ Vdc}, \\ \text{T}_{in-} = 0 \text{ V}, \text{ V}_{in+} \geq 1.0 \text{ Vdc}, \text{ V}_{O} = 30 \text{ Vdc}, \end{array} $	I _{OL}	-	0.1	-	-	0.1	-	nA
$T_{low} \le T_A \le T_{high}$	<u>.</u>	-	-	1000	-	-	1000	
$ \begin{array}{l} \text{Supply Current} \\ \text{R}_L = & \infty \text{ Both Comparators, } \text{T}_A = 25^\circ\text{C} \\ \text{R}_L = & \infty \text{ Both Comparators, } \text{V}_{CC} = 30 \text{ V} \end{array} $	I _{CC}		0.4 -	1.0 2.5		0.4 -	1.0 2.5	mA

ELECTRICAL CHARACTERISTICS ($V_{CC} = 5.0 \text{ Vdc}, T_{low} \le T_A \le T_{high}$, unless otherwise noted.)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

 $\begin{array}{l} LM293 \ T_{low} = -25^{\circ}\text{C}, \ T_{high} = +85^{\circ}\text{C} \\ LM393, \ LM393\text{E} \ T_{low} = 0^{\circ}\text{C}, \ T_{high} = +70^{\circ}\text{C} \\ LM2903, \ LM2903\text{E} \ T_{low} = -40^{\circ}\text{C}, \ T_{high} = +105^{\circ}\text{C} \\ LM2903V \ \& \ NCV2903 \ T_{low} = -40^{\circ}\text{C}, \ T_{high} = +125^{\circ}\text{C} \\ \end{array}$

NCV2903 is qualified for automotive use.

4. The maximum output current may be as high as 20 mA, independent of the magnitude of V_{CC}, output short circuits to V_{CC} can cause excessive heating and eventual destruction.

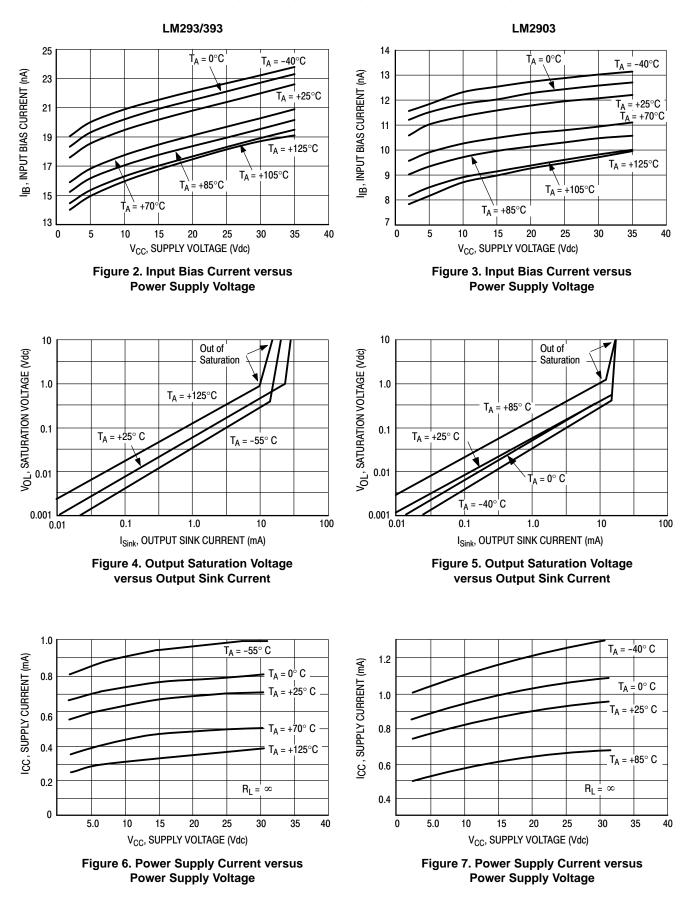
5. At output switch point, $V_0 \simeq 1.4$ Vdc, $R_S = 0 \Omega$ with V_{CC} from 5.0 Vdc to 30 Vdc, and over the full input common mode range $(0 \text{ V to V}_{CC} = -1.5 \text{ V}).$

6. Due to the PNP transistor inputs, bias current will flow out of the inputs. This current is essentially constant, independent of the output state, therefore, no loading changes will exist on the input lines.

7. Input common mode of either input should not be permitted to go more than 0.3 V negative of ground or minus supply. The upper limit of common mode range is V_{CC} –1.5 V.

8. Response time is specified with a 100 mV step and 5.0 mV of overdrive. With larger magnitudes of overdrive faster response times are obtainable.

9. The comparator will exhibit proper output state if one of the inputs becomes greater than V_{CC}, the other input must remain within the common mode range. The low input state must not be less than -0.3 V of ground or minus supply.



APPLICATIONS INFORMATION

These dual comparators feature high gain, wide bandwidth characteristics. This gives the device oscillation tendencies if the outputs are capacitively coupled to the inputs via stray capacitance. This oscillation manifests itself during output transitions (V_{OL} to V_{OH}). To alleviate this situation, input resistors <10 k Ω should be used.

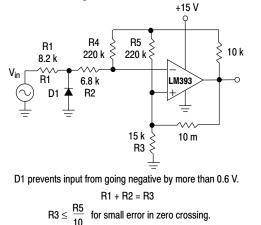


Figure 8. Zero Crossing Detector (Single Supply)

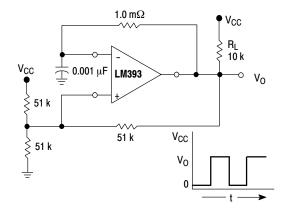
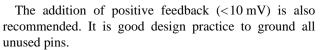
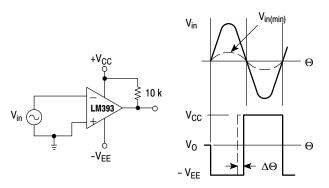


Figure 10. Free–Running Square–Wave Oscillator

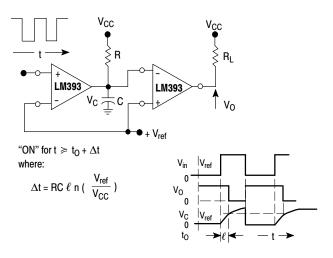


Differential input voltages may be larger than supply voltage without damaging the comparator's inputs. Voltages more negative than -0.3 V should not be used.

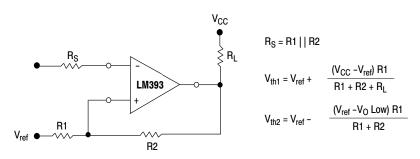


 $V_{in(min)} \approx 0.4$ V peak for 1% phase distortion ($\Delta \Theta$).

Figure 9. Zero Crossing Detector (Split Supply)

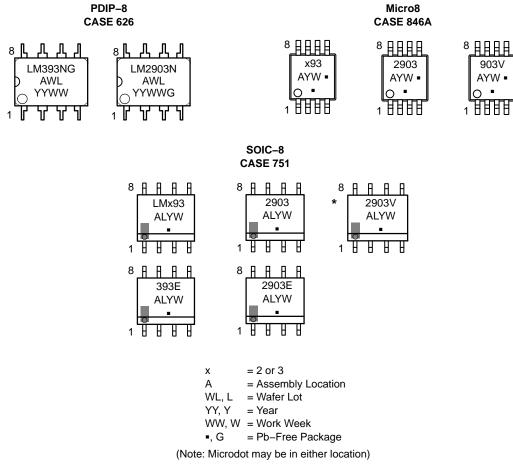








MARKING DIAGRAMS



*This marking diagram also applies to NCV2903DR2G

ORDERING INFORMATION

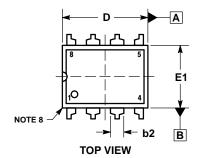
Device	Operating Temperature Range	Package	Shipping [†]
LM293DG		SOIC-8 (Pb-Free)	98 Units / Rail
LM293DR2G	-25°C to +85°C		2500 / Tape & Reel
LM293DMR2G	-23 0 10 100 0	Micro8 (Pb–Free)	4000 / Tape and Reel
LM393DG		SOIC-8	98 Units / Rail
LM393DR2G		(Pb-Free)	2500 / Tape & Reel
LM393EDR2G	0°C to +70°C	SOIC-8 (Pb-Free)	2500 / Tape & Reel
LM393NG		PDIP-8 (Pb-Free)	50 Units / Rail
LM393DMR2G		Micro8 (Pb–Free)	4000 / Tape and Reel
LM2903DG		SOIC-8 (Pb-Free)	98 Units / Rail
LM2903DR2G			2500 / Tape & Reel
LM2903EDR2G	-40°C to +105°C	SOIC-8 (Pb-Free)	2500 / Tape & Reel
LM2903DMR2G		Micro8 (Pb–Free)	4000 / Tape and Reel
LM2903NG		PDIP-8 (Pb-Free)	50 Units / Rail
LM2903VDG		SOIC-8	98 Units / Rail
LM2903VDR2G		(Pb-Free)	2500 / Tape & Reel
LM2903VNG	-40°C to +125°C	PDIP-8 (Pb-Free)	50 Units / Rail
NCV2903DR2G*		SOIC-8 (Pb-Free)	2500 / Tape & Reel
NCV2903DMR2G*		Micro8 (Pb–Free)	4000 / Tape & Reel

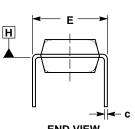
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

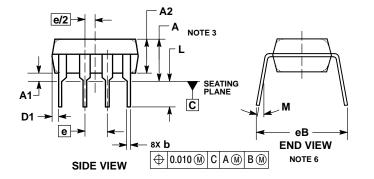
PACKAGE DIMENSIONS

PDIP-8 N, AN, VN SUFFIX CASE 626-05 **ISSUE P**





END VIEW WITH LEADS CONSTRAINED NOTE 5



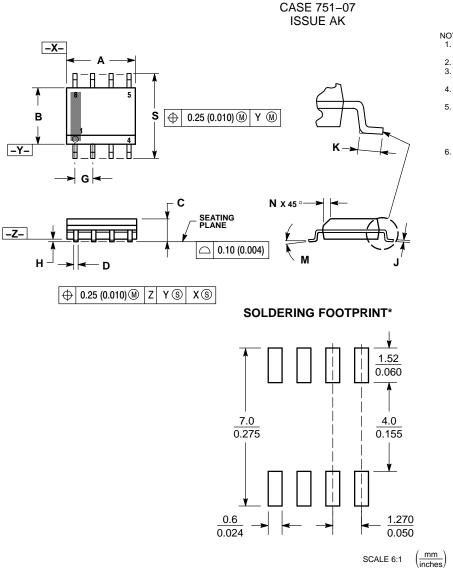
NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: INCHES.
- DIMENSIONS A, AI AND L ARE MEASURED WITH THE PACK-AGE SEATED IN JEDEC SEATING PLANE GAUGE GS-3.
 DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE
- NOT TO EXCEED 0.10 INCH. 5. DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.
- 6. DIMENSION eB IS MEASURED AT THE LEAD TIPS WITH THE
- LEADS UNCONSTRAINED. DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY. PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE 7.
- 8. CORNERS).

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α		0.210		5.33	
A1	0.015		0.38		
A2	0.115	0.195	2.92	4.95	
b	0.014	0.022	0.35	0.56	
b2	0.060) TYP	1.52 TYP		
С	0.008	0.014	0.20	0.36	
D	0.355	0.400	9.02	10.16	
D1	0.005		0.13		
E	0.300	0.325	7.62	8.26	
E1	0.240	0.280	6.10	7.11	
е	0.100	0.100 BSC		BSC	
eB		0.430		10.92	
L	0.115	0.150	2.92	3.81	
М		10°		10°	

PACKAGE DIMENSIONS

SOIC-8 NB



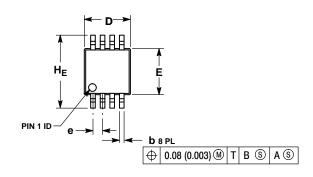
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

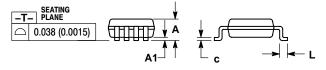
- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION. MAXIMUM MOLD PROTRUSION 0.15 (0.006)
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

	MILLIN	IETERS	INCHES				
DIM	MIN	MAX	MIN	MAX			
Α	4.80	5.00	0.189	0.197			
В	3.80	4.00	0.150	0.157			
С	1.35	1.75	0.053	0.069			
D	0.33	0.51	0.013	0.020			
G	1.27	1.27 BSC		0.050 BSC			
н	0.10	0.25	0.004	0.010			
J	0.19	0.25	0.007	0.010			
к	0.40	1.27	0.016	0.050			
М	0 °	8 °	0 °	8 °			
Ν	0.25	0.50	0.010	0.020			
S	5.80	6.20	0.228	0.244			

PACKAGE DIMENSIONS

Micro8[™] CASE 846A-02 **ISSUE J**





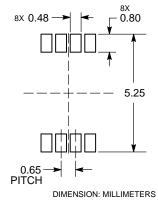
NOTES

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- 0.13 (0.000) PER SIDE. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. 846A-01 OBSOLETE, NEW STANDARD 846A-02. 5.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α			1.10		-	0.043
A1	0.05	0.08	0.15	0.002	0.003	0.006
b	0.25	0.33	0.40	0.010	0.013	0.016
С	0.13	0.18	0.23	0.005	0.007	0.009
D	2.90	3.00	3.10	0.114	0.118	0.122
E	2.90	3.00	3.10	0.114	0.118	0.122
е		0.65 BSC		0.026 BSC		
L	0.40	0.55	0.70	0.016	0.021	0.028
HE	4.75	4.90	5.05	0.187	0.193	0.199





*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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